# Onsemi

# **General Purpose** Transistors

**NPN Silicon** 

# BCW32LT1G

### Features

- NSV Prefix for Automotive and Other Applications Requiring Unique Site and Control Change Requirements; AEC-Q101 Qualified and PPAP Capable
- These Devices are Pb-Free, Halogen Free/BFR Free and are RoHS Compliant

### **MAXIMUM RATINGS**

Symbol	Rating	Value	Unit
V <sub>CEO</sub>	Collector-Emitter Voltage	32	Vdc
V <sub>CBO</sub>	Collector-Base Voltage	32	Vdc
V <sub>EBO</sub>	Emitter-Base Voltage	5.0	Vdc
Ι <sub>C</sub>	Collector Current – Continuous	100	mAdc

Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.

# **THERMAL CHARACTERISTICS**

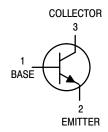
Symbol	Characteristic	Value	Unit
PD	Total Device Dissipation FR-5 Board <sup>(1)</sup> $T_A = 25^{\circ}C$ Derate above 25°C	225 1.8	mW mW/°C
$R_{ hetaJA}$	Thermal Resistance, Junction–to–Ambient	556	°C/W
P <sub>D</sub>	Total Device Dissipation Alumina Substrate, <sup>(2)</sup> T <sub>A</sub> = 25°C Derate above 25°C	300 2.4	mW mW/°C
$R_{ hetaJA}$	Thermal Resistance, Junction-to-Ambient	417	°C/W
T <sub>J</sub> , T <sub>stg</sub>	Junction and Storage Temperature	–55 to +150	°C

1. FR-5 =  $1.0 \times 0.75 \times 0.062$  in.

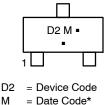
2. Alumina =  $0.4 \times 0.3 \times 0.024$  in. 99.5% alumina.



SOT-23 (TO-236) **CASE 318 STYLE 6** 



# **MARKING DIAGRAM**



Μ

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= Pb-Free Package (Note: Microdot may be in either location)

\*Date Code orientation and/or overbar may vary depending upon manufacturing location.

# **ORDERING INFORMATION**

Device	Package	Shipping <sup>†</sup>
BCW32LT1G	SOT-23 (Pb-Free)	3000 / Tape & Reel
NSVBCW32LT1G	SOT-23 (Pb-Free)	3000 / Tape & Reel

+For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

#### ELECTRICAL CHARACTERISTICS (T<sub>A</sub> = 25°C unless otherwise noted)

Symbol	Characteristic		Тур	Max	Unit
OFF CHARACTERISTICS					
V <sub>(BR)CEO</sub>	Collector – Emitter Breakdown Voltage ( $I_C = 2.0 \text{ mAdc}, V_{EB} = 0$ )	32	-	_	Vdc
V <sub>(BR)CBO</sub>	Collector – Base Breakdown Voltage (I <sub>C</sub> = 10 μAdc, I <sub>E</sub> = 0)	32	-	_	Vdc
$V_{(BR)EBO}$ Emitter – Base Breakdown Voltage (I <sub>E</sub> = 10 µAdc, I <sub>C</sub> = 0)		5.0	-	-	Vdc
I <sub>CBO</sub>	Collector Cutoff Current ( $V_{CB} = 32 \text{ Vdc}, I_E = 0$ ) ( $V_{CB} = 32 \text{ Vdc}, I_E = 0, T_A = 100^{\circ}\text{C}$ )			100 10	nAdc μAdc

#### **ON CHARACTERISTICS**

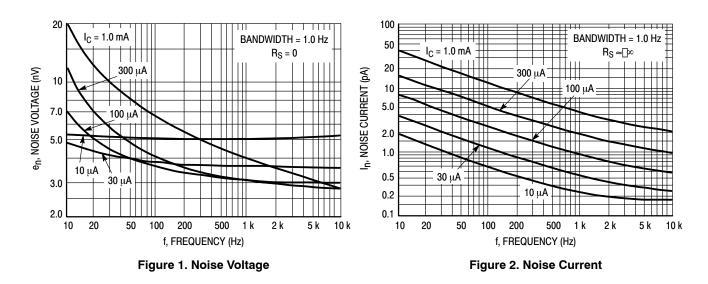
h <sub>FE</sub>	DC Current Gain (I <sub>C</sub> = 2.0 mAdc, V <sub>CE</sub> = 5.0 Vdc)	200	-	450	_
V <sub>CE(sat)</sub>	Collector – Emitter Saturation Voltage $(I_{C} = 10 \text{ mAdc}, I_{B} = 0.5 \text{ mAdc})$	-	-	0.25	Vdc
V <sub>BE(on)</sub>	Base – Emitter On Voltage $(I_C = 2.0 \text{ mAdc}, V_{CE} = 5.0 \text{ Vdc})$	0.55	-	0.70	Vdc

#### SMALL-SIGNAL CHARACTERISTICS

C <sub>obo</sub>	Output Capacitance (I <sub>E</sub> = 0, V <sub>CB</sub> = 10 Vdc, f = 1.0 MHz)	-	_	4.0	pF
NF	Noise Figure (I <sub>C</sub> = 0.2 mAdc, V <sub>CE</sub> = 5.0 Vdc, R <sub>S</sub> = 2.0 k $\Omega$ , f = 1.0 kHz, BW = 200 Hz)	-	-	10	dB

Product parametric performance is indicated in the Electrical Characteristics for the listed test conditions, unless otherwise noted. Product performance may not be indicated by the Electrical Characteristics if operated under different conditions.

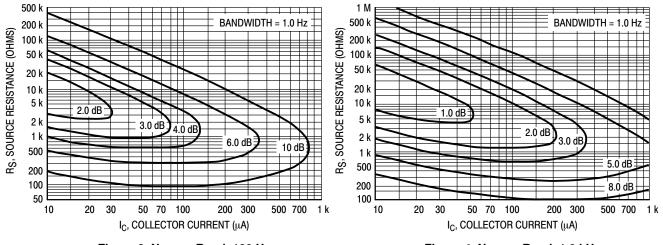
# **TYPICAL NOISE CHARACTERISTICS**



 $(V_{CE} = 5.0 \text{ Vdc}, T_A = 25^{\circ}C)$ 

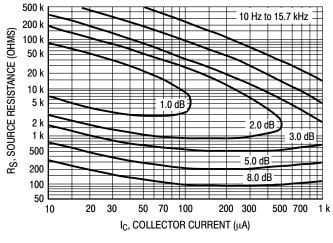
# NOISE FIGURE CONTOURS

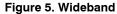
 $(V_{CE}=5.0~Vdc,~T_{A}=25^{\circ}C)$ 











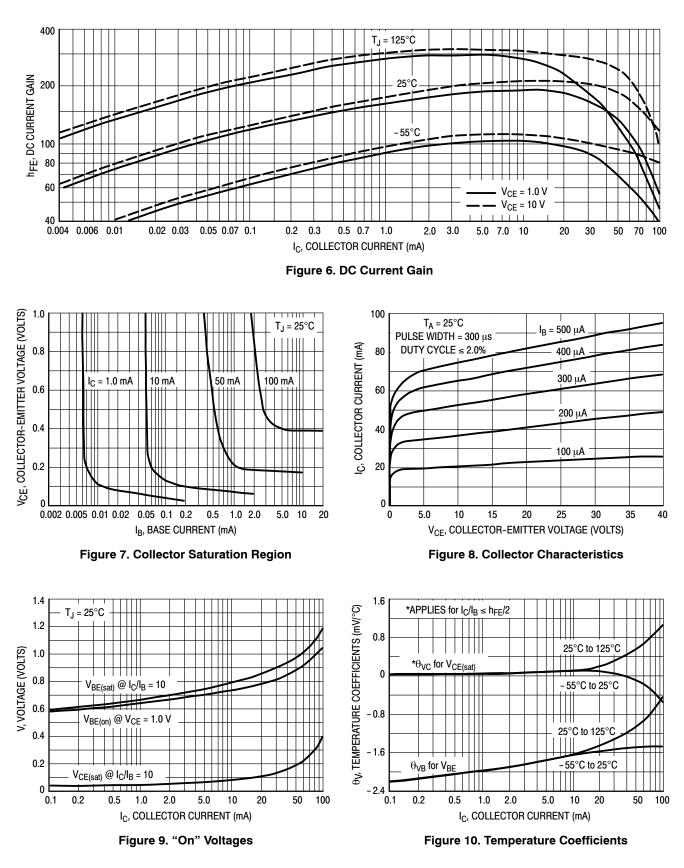
Noise Figure is defined as:

$$NF = 20 \log_{10} \left( \frac{e_{n}^{2} + 4KTR_{S} + I_{n}^{2}R_{S}^{2}}{4KTR_{S}} \right)^{1/2}$$

 $e_n$  = Noise Voltage of the Transistor referred to the input. (Figure 3) I = Noise Current of the Transistor referred to the input. <sub>n</sub> (Figure 4)

- K = Boltzman's Constant (1.38 x  $10^{-23}$  j/°K)
- T = Temperature of the Source Resistance (°K)
- $R = Source Resistance (\Omega)$
- S

# **TYPICAL STATIC CHARACTERISTICS**



# **TYPICAL DYNAMIC CHARACTERISTICS**

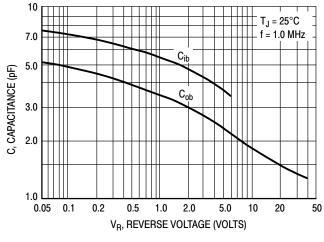


Figure 11. Capacitance

# semi



#### SOT-23 (TO-236) 2.90x1.30x1.00 1.90P **CASE 318**

**ISSUE AU** 

DATE 14 AUG 2024













XXX = Specific Device Code М = Date Code

= Pb-Free Package .

\*This information is generic. Please refer to device data sheet for actual part marking. Pb-Free indicator, "G" or microdot "•", may or may not be present. Some products may not follow the Generic Marking.



MILLIMETERS						
DIM	MIN	NOM	МАХ			
А	0.89	1.00	1.11			
A1	0.01	0.06	0.10			
b	0.37	0.44	0.50			
с	0.08	0.14	0.20			
D	2.80	2.90	3.04			
E	1.20	1.30	1.40			
е	1.78	1.90	2.04			
L	0.30	0.43	0.55			
L1	0.35	0.54	0.69			
Ηe	2.10	2.40	2.64			
Т	0°		10°			

NOTES:

DIMENSIONING AND TOLERANCING PER ASME Y14.5M, 2018. CONTROLLING DIMENSIONS: 1.

2. MILLIMETERS.

MILLIME IERS. MAXIMUM LEAD THICKNESS INCLUDES LEAD FINISH. MINIMUM LEAD THICKNESS IS THE MINIMUM THICKNESS OF THE 3.

BASE MATERIAL. DIMENSIONS D AND E DO NOT INCLUDE MOLD FLASH, 4. PROTRUSIONS, OR GATE BURRS.

#### RECOMMENDED MOUNTING FOOTPRINT

\* For additional information on our Pb-Free strategy and soldering details, please download the onsemi Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

# **STYLES ON PAGE 2**

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#### SOT-23 (TO-236) 2.90x1.30x1.00 1.90P **CÁSE 318** ISSUE AU

DATE 14 AUG 2024

STYLE 1 THRU 5: CANCELLED	STYLE 6: PIN 1. BASE 2. EMITTER 3. COLLECTOR	STYLE 7: PIN 1. EMITTER 2. BASE 3. COLLECTOR	STYLE 8: PIN 1. ANODE 2. NO CONNECTION 3. CATHODE	I	
STYLE 9:	STYLE 10:	STYLE 11:	STYLE 12:	STYLE 13:	STYLE 14:
PIN 1. ANODE	PIN 1. DRAIN	PIN 1. ANODE	PIN 1. CATHODE	PIN 1. SOURCE	PIN 1. CATHODE
2. ANODE	2. SOURCE	2. CATHODE	2. CATHODE	2. DRAIN	2. GATE
3. CATHODE	3. GATE	3. CATHODE-ANODE	3. ANODE	3. GATE	3. ANODE
STYLE 15:	STYLE 16:	STYLE 17:	STYLE 18:	STYLE 19:	STYLE 20:
PIN 1. GATE	PIN 1. ANODE	PIN 1. NO CONNECTION	PIN 1. NO CONNECTION	I PIN 1. CATHODE	PIN 1. CATHODE
2. CATHODE	2. CATHODE	2. ANODE	2. CATHODE	2. ANODE	2. ANODE
3. ANODE	3. CATHODE	3. CATHODE	3. ANODE	3. CATHODE-ANODE	3. GATE
STYLE 21:	STYLE 22:	STYLE 23:	STYLE 24:	STYLE 25:	STYLE 26:
PIN 1. GATE	PIN 1. RETURN	PIN 1. ANODE	PIN 1. GATE	PIN 1. ANODE	PIN 1. CATHODE
2. SOURCE	2. OUTPUT	2. ANODE	2. DRAIN	2. CATHODE	2. ANODE
3. DRAIN	3. INPUT	3. CATHODE	3. SOURCE	3. GATE	3. NO CONNECTION
STYLE 27: PIN 1. CATHODE 2. CATHODE 3. CATHODE	STYLE 28: PIN 1. ANODE 2. ANODE 3. ANODE				

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